

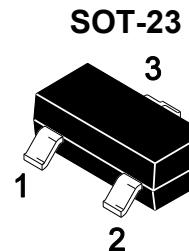


MMBTRC116SS~MMBTRC122SS

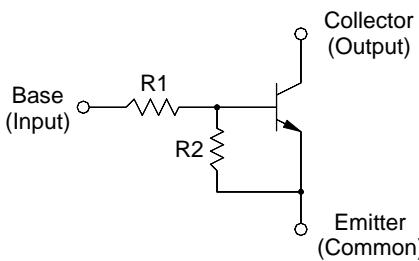
NPN Digital Transistor

Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



Equivalent Circuit



1.Base 2.Emitter 3.Collector

Resistor Values/Marking Code

Type	R1 (KΩ)			R2 (KΩ)			Marking Code
	Min.	Typ.	Max.	Min.	Typ.	Max.	
MMBTRC116SS	0.7	1	1.3	7	10	13	16BR
MMBTRC117SS	1.54	2.2	2.86	1.54	2.2	2.86	17BR
MMBTRC118SS	1.54	2.2	2.86	7	10	13	18BR
MMBTRC119SS	3.29	4.7	6.11	7	10	13	19BR
MMBTRC120SS	7	10	13	3.29	4.7	6.11	20BR
MMBTRC121SS	32.9	47	61.1	7	10	13	21BR
MMBTRC122SS	70	100	130	70	100	130	22BR

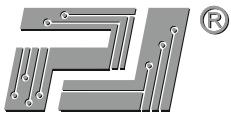


MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Output Voltage	V_O	50	V
Input Voltage	MMBTRC116SS	10,-5	V
	MMBTRC117SS	12,-10	
	MMBTRC118SS	12,-5	
	MMBTRC119SS	20,-7	
	MMBTRC120SS	30,-10	
	MMBTRC121SS	40,-15	
	MMBTRC122SS	40,-10	
Output Current	I_O	100	mA
Maximum Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

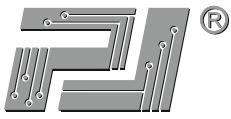


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Electrical Characteristics ($T_A=25^\circ\text{C}$)

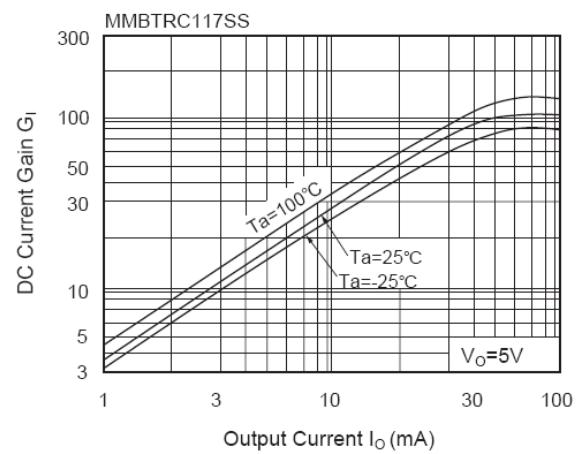
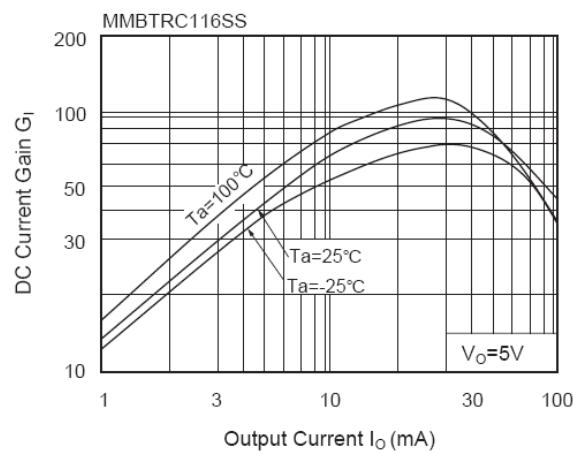
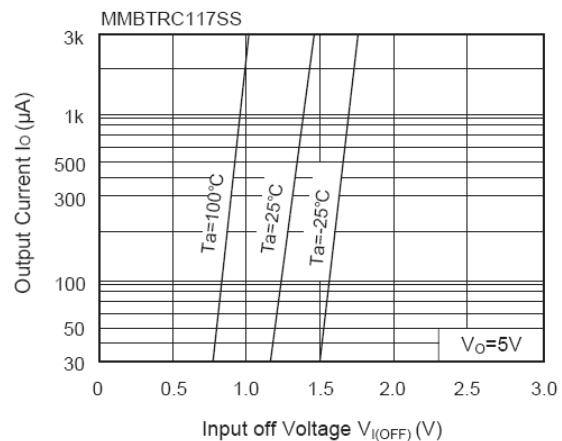
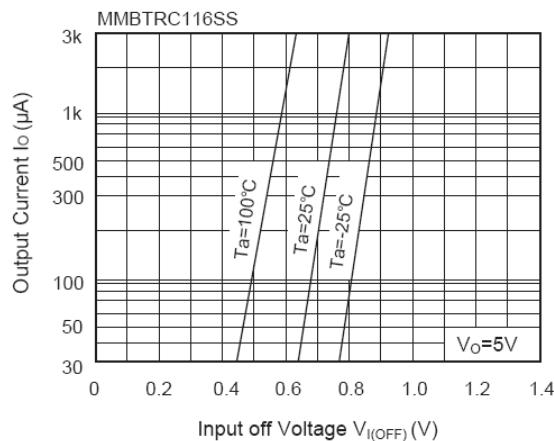
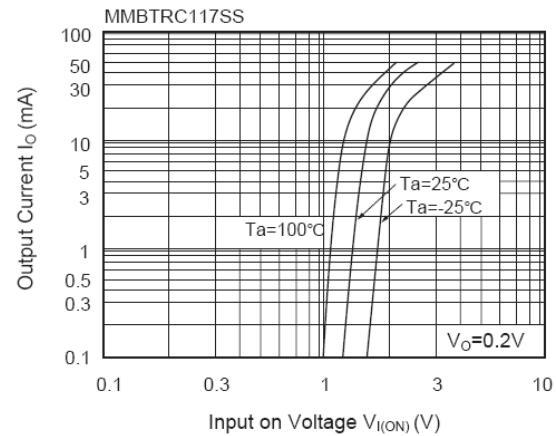
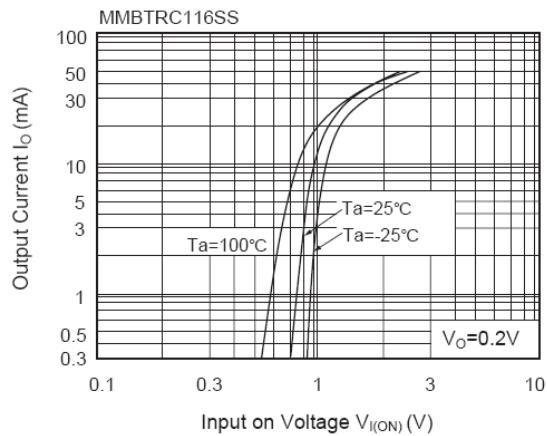
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_O = 5 \text{ V}$, $I_O = 5 \text{ mA}$	G_I	33	--	--	--
at $V_O = 5 \text{ V}$, $I_O = 20 \text{ mA}$		20	--	--	
at $V_O = 5 \text{ V}$, $I_O = 10 \text{ mA}$		33	--	--	
at $V_O = 5 \text{ V}$, $I_O = 10 \text{ mA}$		30	--	--	
at $V_O = 5 \text{ V}$, $I_O = 10 \text{ mA}$		24	--	--	
at $V_O = 5 \text{ V}$, $I_O = 5 \text{ mA}$		33	--	--	
at $V_O = 5 \text{ V}$, $I_O = 5 \text{ mA}$		62	--	--	
Output Cutoff Current at $V_O = 50 \text{ V}$	$I_{O(\text{OFF})}$	--	--	500	nA
Input Current at $V_I = 5 \text{ V}$	I_I				mA
		--	--	7.2	
		--	--	3.8	
		--	--	3.8	
		--	--	1.8	
		--	--	0.88	
		--	--	0.16	
		--	--	0.15	
Output Voltage (ON)	$V_{O(\text{ON})}$				
at $I_O = 10 \text{ mA}$, $I_I = 0.5 \text{ mA}$		--	--	0.3	V
at $I_O = 5 \text{ mA}$, $I_I = 0.25 \text{ mA}$	MMBTRC122SS	--	--	0.3	
Input Voltage (ON)	$V_{I(\text{ON})}$				V
at $V_O = 0.3 \text{ V}$, $I_O = 20 \text{ mA}$	MMBTRC116SS	--	--	3	
at $V_O = 0.3 \text{ V}$, $I_O = 20 \text{ mA}$	MMBTRC117SS	--	--	3	
at $V_O = 0.3 \text{ V}$, $I_O = 20 \text{ mA}$	MMBTRC118SS	--	--	3	
at $V_O = 0.3 \text{ V}$, $I_O = 20 \text{ mA}$	MMBTRC119SS	--	--	2.5	
at $V_O = 0.3 \text{ V}$, $I_O = 2 \text{ mA}$	MMBTRC120SS	--	--	3	
at $V_O = 0.3 \text{ V}$, $I_O = 2 \text{ mA}$	MMBTRC121SS	--	--	5	
at $V_O = 0.3 \text{ V}$, $I_O = 1 \text{ mA}$	MMBTRC122SS	--	--	3	
Input Voltage (OFF)	$V_{I(\text{OFF})}$				V
at $V_{CC} = 5 \text{ V}$, $I_O = 100 \mu\text{A}$	MMBTRC116SS	0.3	--	--	
	MMBTRC117SS	0.5	--	--	
	MMBTRC118SS	0.3	--	--	
	MMBTRC119SS	0.3	--	--	
	MMBTRC120SS	0.8	--	--	
	MMBTRC121SS	1	--	--	
	MMBTRC122SS	0.5	--	--	
Transition Frequency at $V_O = 10 \text{ V}$, $I_O = 5 \text{ mA}$	f_T	--	250	--	MHz

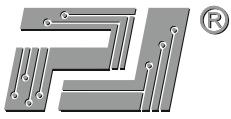


MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor

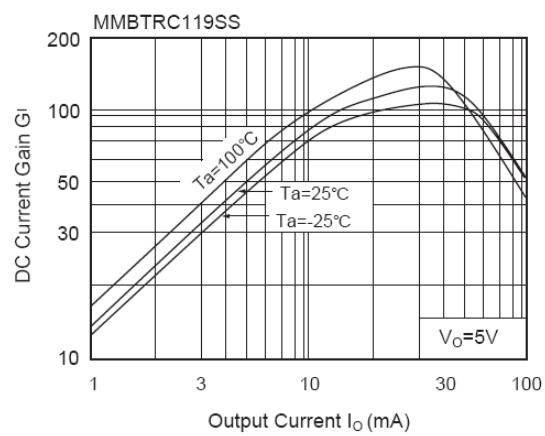
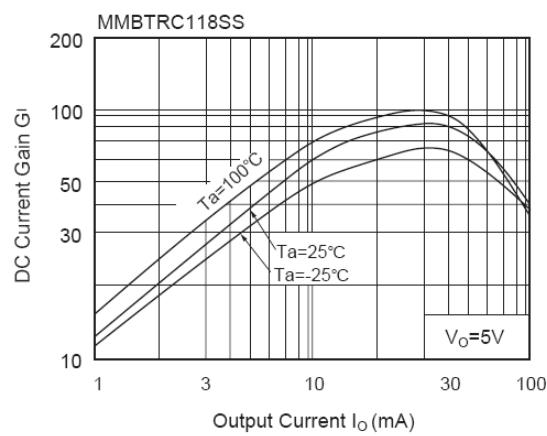
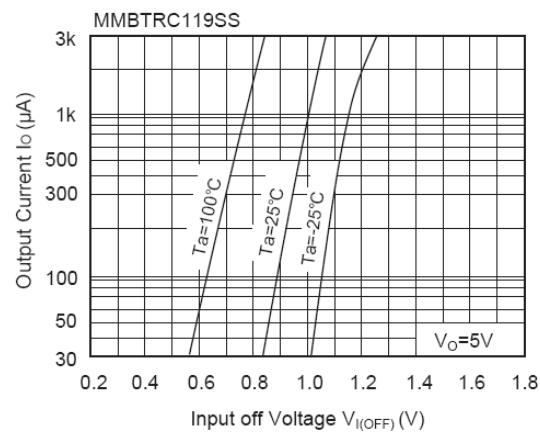
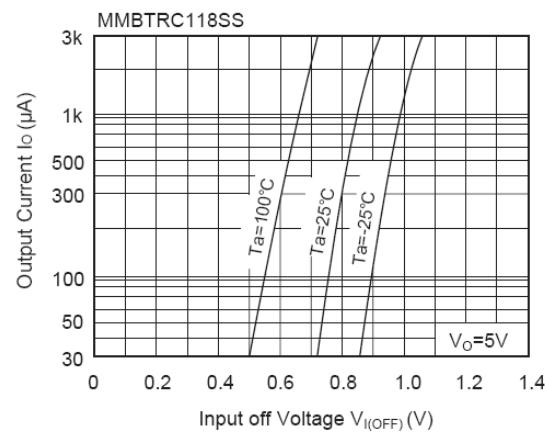
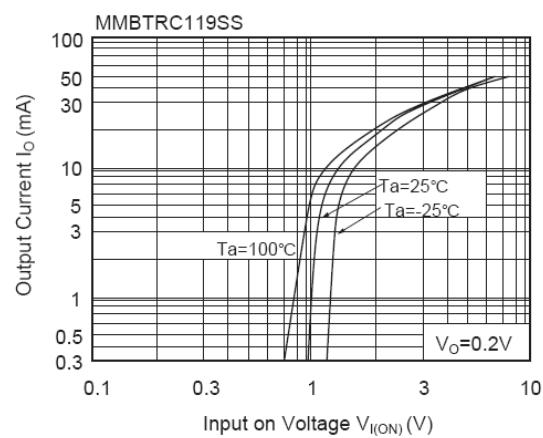
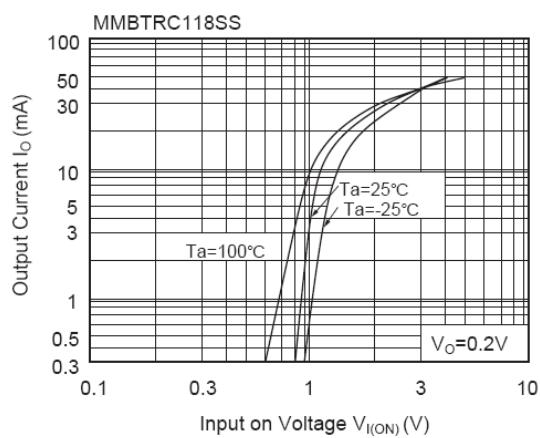
Typical Characteristic Curves

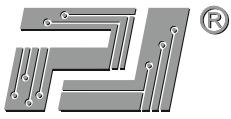




MMBTRC116SS~MMBTRC122SS

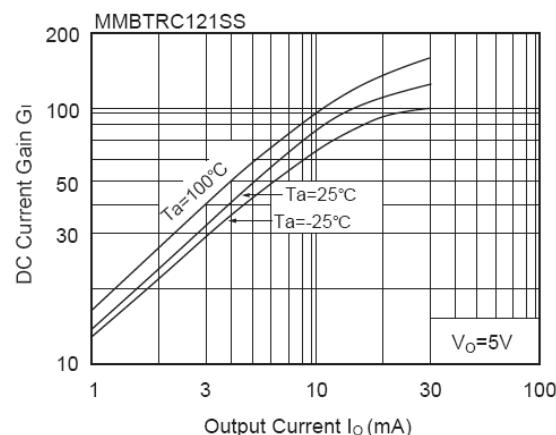
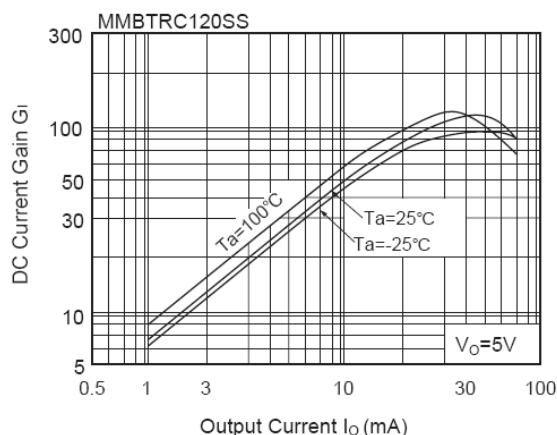
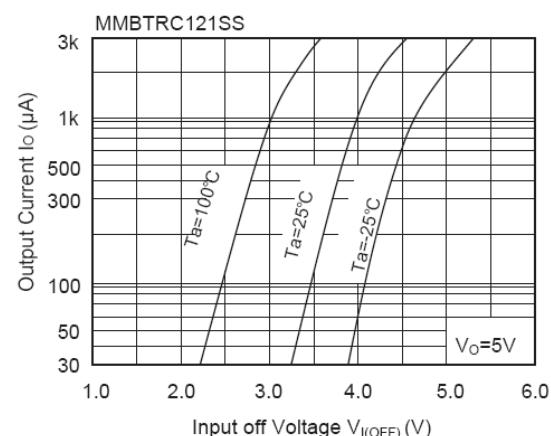
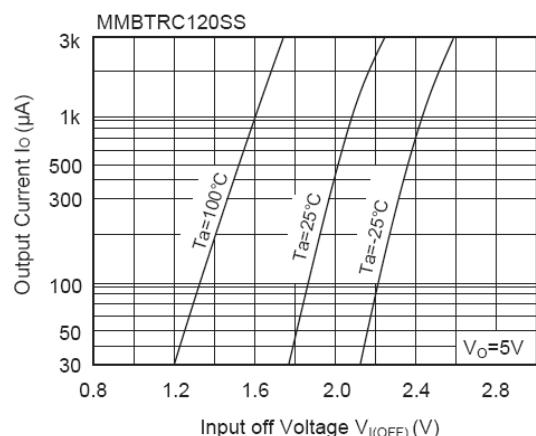
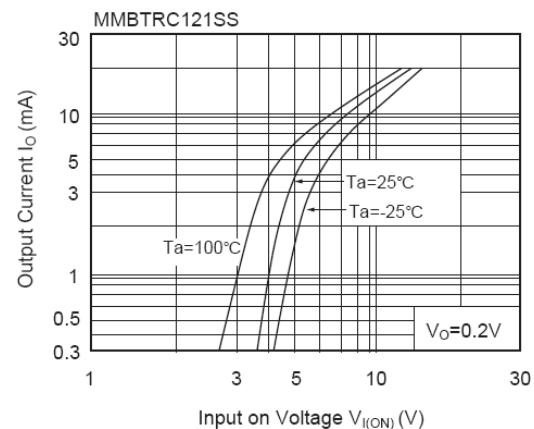
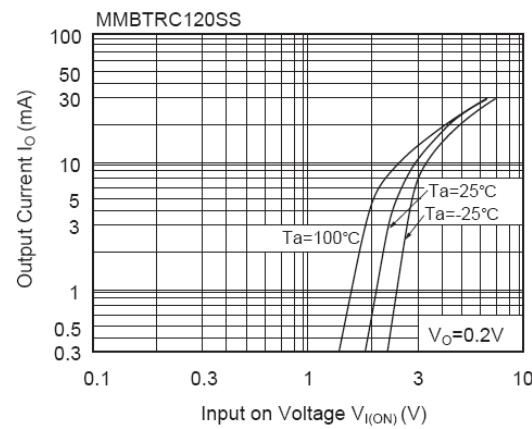
NPN Digital Transistor





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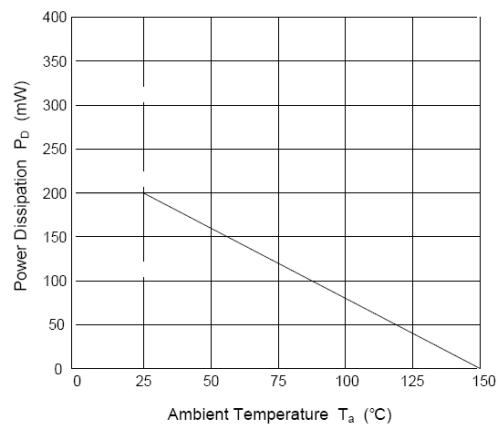
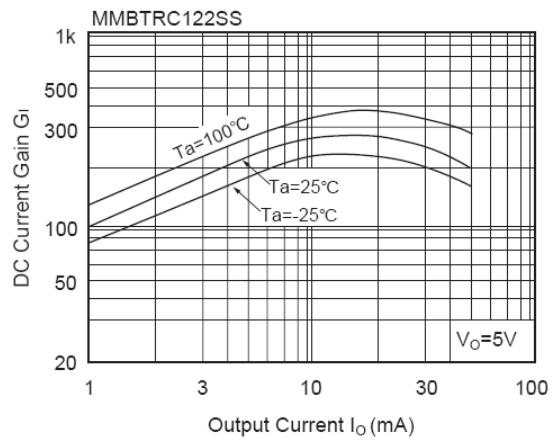
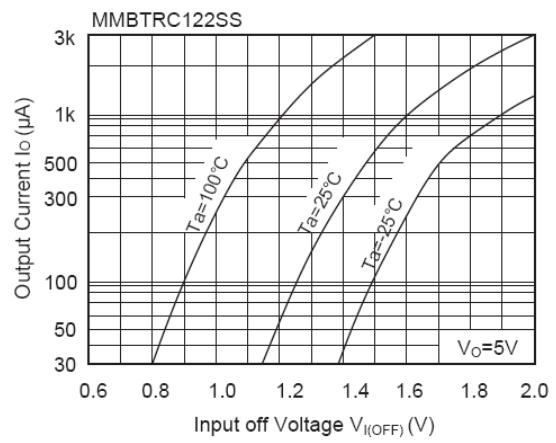
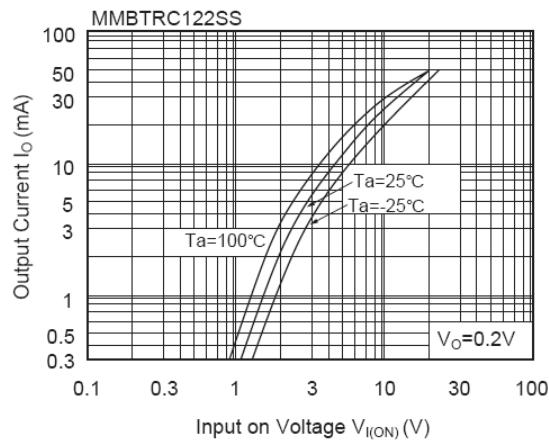
NPN Digital Transistor

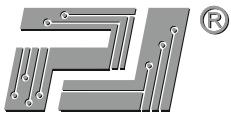




MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor





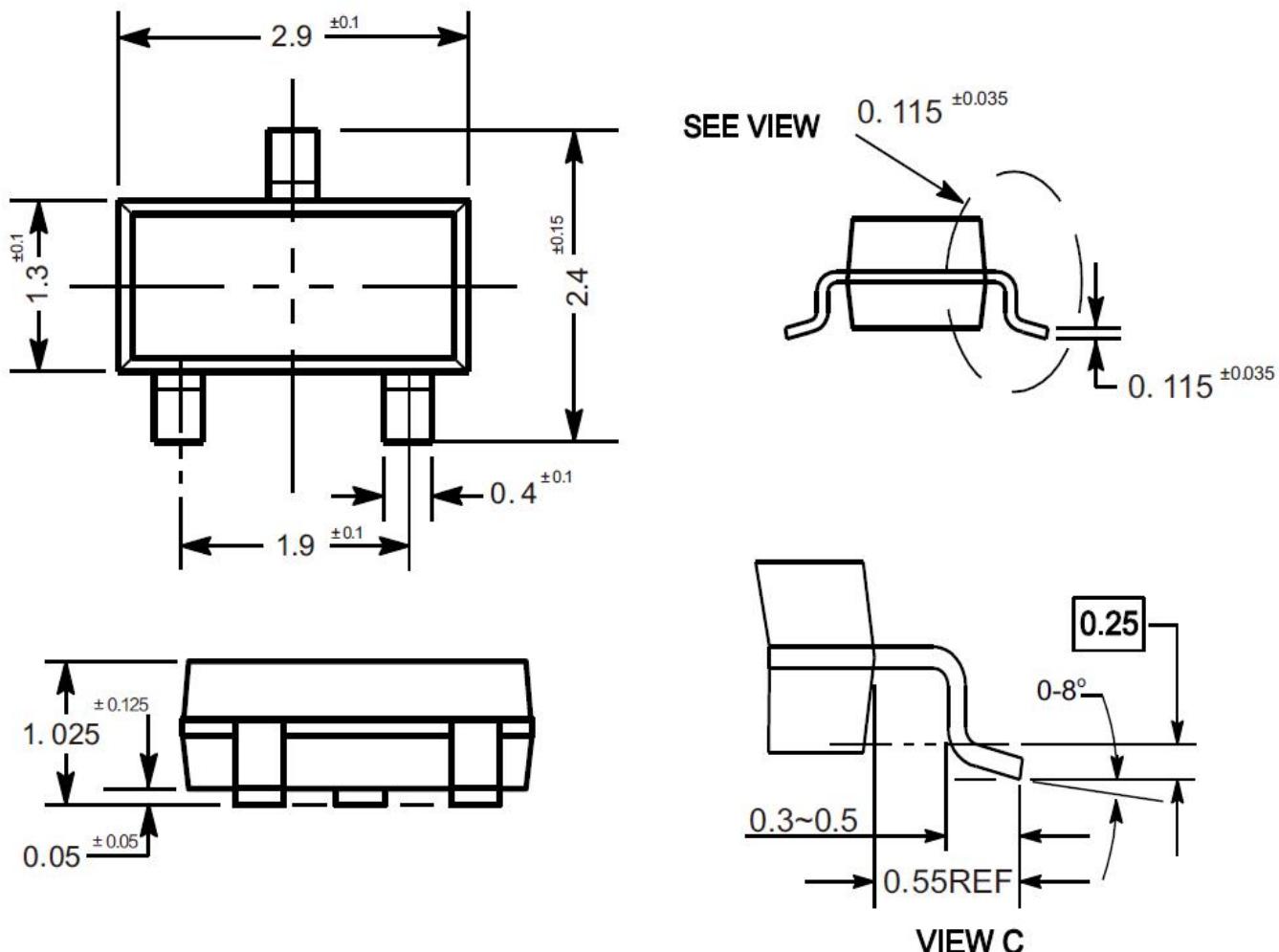
MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor

Package Outline

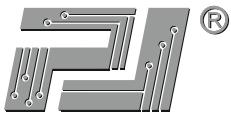
SOT-23

Dimensions in mm



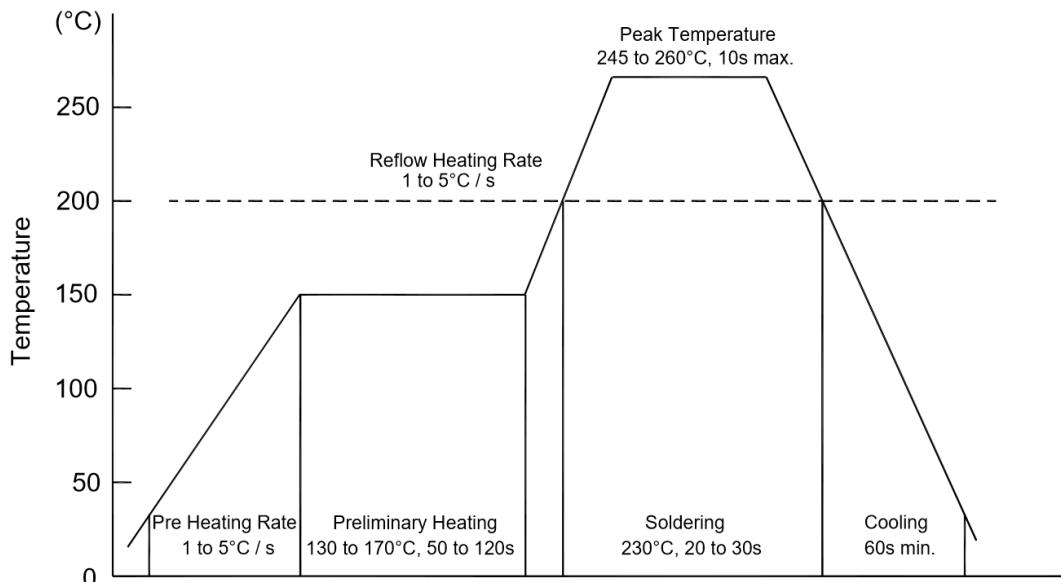
Ordering Information

Device	Package	Shipping
MMBTRC116SS~MMBTRC122SS	SOT-23	3,000PCS/Reel&7inches



Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

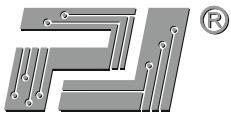
- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

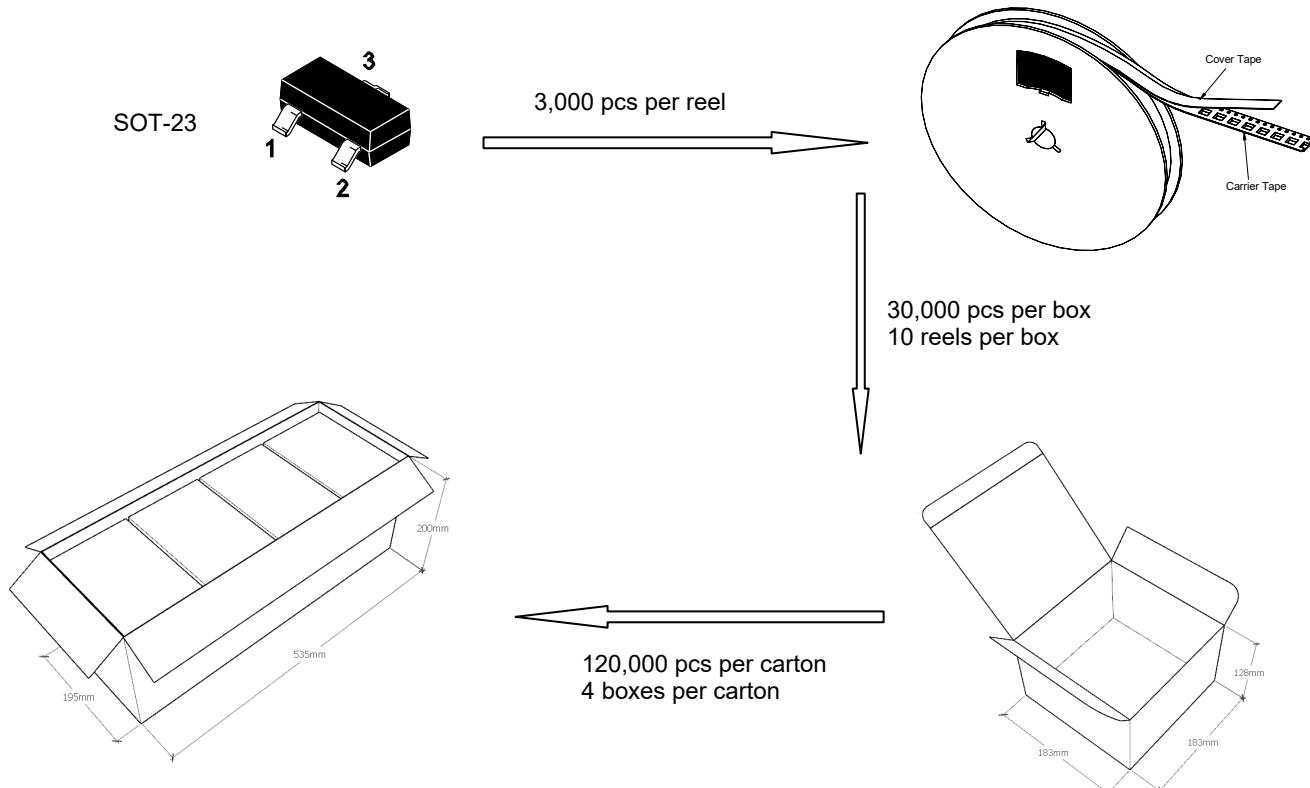


MMBTRC101SS~MMBTRC106SS

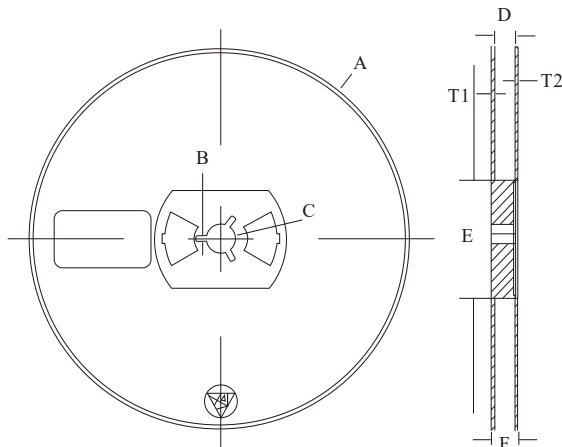
NPN Digital Transistor

Package Specifications

- The method of packaging



◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	$\varnothing 177.8 \pm 1$
B	2.7 ± 0.2
C	$\varnothing 13.5 \pm 0.2$
E	$\varnothing 54.5 \pm 0.2$
F	12.3 ± 0.3
D	$9.6 +2/-0.3$
T1	1.0 ± 0.2
T2	1.2 ± 0.2

Reel (7")

